

Isolated Precision Half-Bridge Driver, 4.0 A Output

Data Sheet **[ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf)**

FEATURES

4.0 A peak output current Working voltage High-side or low-side relative to input: 565 V peak High-side to low-side differential: 700 V peak High frequency operation: 1 MHz maximum Precise timing characteristics 64 ns maximum propagation delay 8.5 ns maximum channel-to-channel matching 3.0 V to 5.5 V input voltage 4.5 V to 18 V output drive UVLO supply at 2.8 V V_{DD1} A Version UVLO, V_{DDA} and V_{DDB} (V_{DD2}) at 4.1 V **B Version UVLO, VDDA and VDDB at 6.9 V C Version UVLO, V_{DDA} and V_{DDB} at 10.5 V CMOS input logic levels High common-mode transient immunity: >25 kV/μs High junction temperature operation: 125°C Default low output 5 mm × 5 mm, 13-terminal LGA**

APPLICATIONS

Switching power supplies Isolated IGBT/MOSFET gate drives Industrial inverters

GENERAL DESCRIPTION

The [ADuM7223 i](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf)s a 4.0 A isolated, half-bridge gate driver that employs Analog Devices, Inc., *i*Coupler® technology to provide independent and isolated high-side and low-side outputs. Combining high speed CMOS and monolithic transformer technology, these isolation components provide outstanding performance characteristics superior to alternatives such as the combination of pulse transformers and non-isolated gate drivers. By integrating the isolator and driver in a single package, propagation delay is a maximum of only 64 ns, and the propagation skew from channel to channel is a maximum of only 12 ns at 12 V.

The [ADuM7223 p](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf)rovides two independent isolation channels. Th[e ADuM7223 o](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf)perates with an input supply ranging from 3.0 V to 5.5 V, providing compatibility with lower voltage systems. The outputs operate in a wide range from 4.5 V to 18 V with three output voltage versions available. The 5 mm \times 5 mm, LGA package provides 565 V operating voltage from input to output and 700 V from output to output.

In comparison to gate drivers employing high voltage level translation methodologies, this gate driver offers the benefit of true, galvanic isolation between the input and each output. As a result, this gate driver provides reliable control over the switching characteristics of IGBT/MOSFET configurations over a wide range of positive or negative switching voltages.

FUNCTIONAL BLOCK DIAGRAM

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Last Content Update: 11/01/2016

[Comparable Parts](http://www.analog.com/parametricsearch/en/11102?doc=adum7223.pdf&p0=1&lsrc=pst)^[1]

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[Evaluation Kits](http://www.analog.com/adum7223/evalkits?doc=adum7223.pdf&p0=1&lsrc=ek) \Box

- AD-FMCMOTCON2-EBZ Evaluation Board
- ADuM7223 Evaluation Board

[Documentation](http://www.analog.com/adum7223/documentation?doc=adum7223.pdf&p0=1&lsrc=doc) \Box

Data Sheet

• ADuM7223: Isolated Precision Half-Bridge Driver, 4.0 A Output Data Sheet

User Guides

• UG-657: Evaluation Board for the ADuM7223 *i*Coupler, 4 A, Isolated Precision Half Bridge Driver

[Reference Materials](http://www.analog.com/adum7223/referencematerials?doc=adum7223.pdf&p0=1&lsrc=rm)¹

Informational

• Overcoming Limitations of Optocoupler and High Voltage Gate Driver Solutions

[Design Resources](http://www.analog.com/adum7223/designsources?doc=adum7223.pdf&p0=1&lsrc=dr)^[D]

- ADuM7223 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

[Discussions](http://www.analog.com/adum7223/discussions?doc=adum7223.pdf&p0=1&lsrc=disc) \Box

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REVISION HISTORY

4/14—Rev. 0 to Rev. A

10/13—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS—5 V OPERATION

All voltages are relative to their respective ground. $4.5 \text{ V} \leq \text{V}_{\text{DD1}} \leq 5.5 \text{ V}$, $4.5 \text{ V} \leq \text{V}_{\text{DD2}} \leq 18 \text{ V}$, unless stated otherwise. All minimum/maximum specifications apply over T_J = −40°C to +125°C. All typical specifications are at T_A = 25°C, V_{DD1} = 5 V, V_{DD2} = 12 V. Switching specifications are tested with CMOS signal levels. **Table 1.**

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¹ Short-circuit duration less than 1 μs. Average power must conform to the limit shown under the Absolute Maximum Ratings.
² The minimum pulse width is the shortest pulse width at which the specified timing parameter

² The minimum pulse width is the shortest pulse width at which the specified timing parameter is guaranteed.

³ The maximum data rate is the fastest data rate at which the specified timing parameter is guaranteed.

⁴ t_{out} propagation delay is measured from the time of the input rising logic high threshold, V_{IH}, to the output rising 10% level of the V_{Ox} signal. t_{oHL} propagation delay is measured from the input falling logic low threshold, V_{IL} to the output falling 90% threshold of the V_{ox} signal. Se[e Figure 16 f](#page-11-5)or waveforms of propagation delay parameters.

 5 t_{PSK} is the magnitude of the worst-case difference in t_{DLH} and/or t_{DHL} that is measured betwee[n ADuM7223 u](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf)nits at the same operating temperature, supply voltages, and output load within the recommended operating conditions. Se[e Figure 16 f](#page-11-5)or waveforms of propagation delay parameters.

⁶ Channel-to-channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier.

ELECTRICAL CHARACTERISTICS—3.3 V OPERATION

All voltages are relative to their respective ground. 3.0 V \leq V_{DD1} \leq 3.6 V, 4.5 V \leq V_{DD2} \leq 18 V, unless stated otherwise. All minimum/maximum specifications apply over T_J = −40°C to 125°C. All typical specifications are at T_A = 25°C, V_{DD1} = 3.3 V, V_{DD2} = 12 V. Switching specifications are tested with CMOS signal levels.

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¹ Short-circuit duration less than 1 µs. Average power must conform to the limit shown under th[e Absolute Maximum Ratings.](#page-7-0)

² The minimum pulse width is the shortest pulse width at which the specified timing parameter is guaranteed.

 3 The maximum data rate is the fastest data rate at which the specified timing parameter is guaranteed.

 4 t_{DLH} propagation delay is measured from the time of the input rising logic high threshold, V_{IH}, to the output rising 10% level of the V_{Ox} signal. t_{DHL} propagation delay is measured from the input falling logic low threshold, V_{IL}, to the output falling 90% threshold of the V_{Ox} signal. See [Figure 16](#page-11-5) for waveforms of propagation delay parameters.

 5 t_{PSK} is the magnitude of the worst-case difference in t_{DLH} and/or t_{DHL} that is measured between units at the same operating temperature, supply voltages, and output load within the recommended operating conditions. Se[e Figure 16](#page-11-5) for waveforms of propagation delay parameters.

⁶ Channel-to-channel matching is the absolute value of the difference in propagation delays between any two channels with inputs on the same side of the isolation barrier.

PACKAGE CHARACTERISTICS

INSULATION AND SAFETY-RELATED SPECIFICATIONS Table 4.

¹ Insulation voltage guaranteed by design, not tested in production. Insulation is similar in structure to devices that are tested to 5 kV rms in production.

RECOMMENDED OPERATING CONDITIONS Table 5.

¹ All voltages are relative to their respective ground. See the Applications [Information](#page-11-0) section for information on immunity to external magnetic fields.

² Static common-mode transient immunity is defined as the largest dv/dt between GND₁ and GND_A/GND_B with inputs held either high or low such that the output voltage remains either above 0.8 \times V_{DD2} for V_{IA}/V_{IB} = high, or 0.8 V for V_{IA}/V_{IB} = low. Operation with transients above recommended levels can cause momentary data upsets.

³ Dynamic common-mode transient immunity is defined as the largest dv/dt between GND₁ and GND_A/GND_B with switching edge coincident with the transient test pulse. Operation with transients above recommended levels can cause momentary data upsets.

ABSOLUTE MAXIMUM RATINGS

Ambient temperature = 25°C, unless otherwise noted.

Table 6.

¹ All voltages are relative to their respective ground.

² V_{DDI} and \bar{V}_{DDO} refer to the supply voltages on the input and output sides of a given channel, respectively.

³ Se[e Figure 2](#page-6-3) for information on maximum allowable current for various temperatures.

⁴ Refers to common-mode transients across the insulation barrier. Commonmode transients exceeding the Absolute Maximum Rating can cause latch-up or permanent damage.

Table 7. Maximum Continuous Working Voltage1

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

¹ Refers to continuous voltage magnitude imposed across the isolation barrier. See th[e Insulation Lifetime](#page-13-1) section for more details.

Table 8. Truth Table (Positive Logic)1

 $1 X =$ don't care.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

Figure 3. Pin Configuration

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Table 9. Pin Function Descriptions

TYPICAL PERFORMANCE CHARACTERISTICS

Figure 4. Output Waveform for 2 nF Load with 12 V Output Supply

Figure 5. Output Matching and Rise Time Waveforms for 2 nF Load with 12 V Output Supply

Figure 6. Typical IDD1 Supply Current vs. Frequency

Figure 7. Typical IDDA/IDDB Supply Current vs. Frequency with 2 nF Load

Figure 8. Typical Propagation Delay vs. Junction Temperature

Figure 9. Typical Propagation Delay vs. Input Supply Voltage, VDDA/VDDB = 12 V

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Figure 10. Typical Propagation Delay vs. Output Supply Voltage, V_{DD1} = 5 V

Figure 12. Typical Propagation Delay, Channel-to-Channel Matching vs. Output Supply Voltage

Figure 13. Typical Propagation Delay (PD) Channel-to-Channel Matching vs. $Temperature, V_{DDA}/V_{DDB} = 12 V$

Figure 14. Typical Output Resistance vs. Output Supply Voltage

Figure 15. Typical Peak Output Current vs. Output Supply Voltage, 1.2 Ω Series Resistance

APPLICATIONS INFORMATION **PRINTED CIRCUIT BOARD (PCB) LAYOUT**

The [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) digital isolator requires no external interface circuitry for the logic interfaces. Power supply bypassing is required at the input and output supply pins. Use a small ceramic capacitor with a value between 0.01 μ F and 0.1 μ F to provide a good high frequency bypass. On the output power supply pins, V_{DDA} or V_{DDB} , it is recommended to add a 10 μ F capacitor in parallel to provide the charge required to drive the gate capacitance at the [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) outputs. Lower values of decoupling can be used provided the designer ensures that voltage drops during switching transients are acceptable. The required decoupling is a function of the gate capacitance being driven versus the acceptable voltage drop. On the output supply pins, avoid bypass capacitor use of vias, or employ multiple vias to reduce the inductance in the bypassing. The total lead length between both ends of the smaller capacitor and the input or output power supply pin must not exceed 20 mm for best performance. For best performance, place bypass capacitors as near to the device as possible.

PROPAGATION DELAY-RELATED PARAMETERS

Propagation delay is a parameter that describes the time it takes a logic signal to propagate through a component. The propagation delay to a logic low output can differ from the propagation delay to a logic high output. Th[e ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) specifies t_{DLH} as the time between the rising input high logic threshold, V_{IH} , to the output rising 10% threshold (see [Figure 16\)](#page-11-5). Likewise, the falling propagation delay, tDHL, is defined as the time between the input falling logic low threshold, V_{IL} , and the output falling 90% threshold. The rise and fall times are dependent on the loading conditions and are not included in the propagation delay, as is the industry standard for gate drivers.

Figure 16. Propagation Delay Parameters

Channel-to-channel matching refers to the maximum amount that the propagation delay differs between channels within a singl[e ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) component.

Propagation delay skew refers to the maximum amount that the propagation delay differs between multipl[e ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) devices operating under the same conditions.

THERMAL LIMITATIONS AND SWITCH LOAD CHARACTERISTICS

For isolated gate drivers, the necessary separation between the input and output circuits prevents the use of a single thermal pad beneath the device, and heat is, therefore, dissipated mainly through the package pins.

Power dissipation within the device is primarily driven by the effective load capacitance being driven, switching frequency, operating voltage, and external series resistance. Power dissipation within each channel can be calculated by

$$
P_{\rm DISSS} = C_{\rm EFF} \times (V_{\rm DDA/B})^2 \times f_{\rm SW} \frac{R_{\rm DSON}}{R_{\rm DSON} + R_{\rm GATE}}
$$

where:

CEFF is the effective capacitance of the load. $V_{DDA/B}$ is the secondary side voltage. *fSW* is the switching frequency. *RDSON* is the internal resistance of th[e ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) (ROA, ROB). *RGATE* is the external gate resistor.

To find temperature rise above ambient temperature, multiply total power dissipation by the θ_{JA} , which is then added to the ambient temperature to find the approximate internal junction temperature of th[e ADuM7223.](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf)

Each of th[e ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) isolator outputs have a thermal shutdown protection function. This function sets an output to a logic low level when the rising junction temperature typically reaches 150°C and turns back on after the junction temperature has fallen from the shutdown value by about 10°C.

OUTPUT LOAD CHARACTERISTICS

The [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) output signals depend on the characteristics of the output load, which is typically an N-channel MOSFET. The driver output response to an N-channel MOSFET load can be modeled with a switch output resistance (R_{SW}) , an inductance due to the PCB trace (L_{TRACE}), a series gate resistor (R_{GATE}), and a gate to source capacitance (CGS), as shown in Figure 17.

R_{SW} is the switch resistance of the interna[l ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) driver output (1.1 Ω typical for turn-on and 0.6 Ω for turn-off). R_{GATE} is the intrinsic gate resistance of the MOSFET and any external series resistance. A MOSFET that requires a 4 A gate driver has a typical intrinsic gate resistance of about 1 Ω and a gate-tosource capacitance (C_{GS}) of between 2 nF and 10 nF. L_{TRACE} is the inductance of the PCB trace, typically a value of 5 nH or less for a well-designed layout with a very short and wide connection from the [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) output to the gate of the MOSFET.

The following equation defines the Q factor of the RLC circuit, which indicates how th[e ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) output responds to a step change. For a well-damped output, Q is less than one. Adding a series gate resistance dampens the output response.

$$
Q = \frac{1}{(R_{SW} + R_{GATE})} \times \sqrt{\frac{L_{TRACE}}{C_{GS}}}
$$

To reduce output ringing, add a series gate resistance to dampen the response. For applications using a load of 1 nF or less, add a series gate resistor of about 5 Ω . It is recommended that the Q factor be below 1 which results in a damped system, with a value of 0.7 as the recommended target.

Figure 17. RLC Model of the Gate of an N-Channel MOSFET

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DC CORRECTNESS AND MAGNETIC FIELD IMMUNITY

Positive and negative logic transitions at the isolator input cause narrow (-1 ns) pulses to be sent to the decoder via the transformer. The decoder is bistable and is, therefore, either set or reset by the pulses, indicating input logic transitions. In the absence of logic transitions of more than 1 μs (typical) at the input, a periodic set of refresh pulses indicative of the correct input state are sent to ensure dc correctness at the output.

If the decoder receives no internal pulses for more than about 3 µs (typical), the input side is assumed to be unpowered or nonfunctional, in which case, the isolator output is forced to a default low state by the watchdog timer circuit. In addition, the outputs are in a low default state while the power is coming up before the UVLO threshold is crossed.

The limitation on the [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) magnetic field immunity is set by the condition in which induced voltage in the transformer receiving coil is sufficiently large to either falsely set or reset the decoder. The following analysis defines the conditions under which this can occur. The 3 V operating condition of the [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) is examined because it represents the most susceptible mode of operation. The pulses at the transformer output have an amplitude greater than 1.0 V. The decoder has a sensing threshold at about 0.5 V, therefore establishing a 0.5 V margin in which induced voltages can be tolerated. The voltage induced across the receiving coil is given by

$$
V = (-d\beta/dt) \sum \pi r_n^2, n = 1, 2, ..., N
$$

where:

 β is the magnetic flux density (gauss).

 r_n is the radius of the nth turn in the receiving coil (cm). *N* is the number of turns in the receiving coil.

Given the geometry of the receiving coil in the [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) and an imposed requirement that the induced voltage is at most

50% of the 0.5 V margin at the decoder, a maximum allowable magnetic field is calculated, as shown i[n Figure 18.](#page-12-2)

Figure 18. Maximum Allowable External Magnetic Flux Density

For example, at a magnetic field frequency of 1 MHz, the maximum allowable magnetic field of 0.2 kgauss induces a voltage of 0.25 V at the receiving coil. This is about 50% of the sensing threshold and does not cause a faulty output transition. Similarly, if such an event were to occur during a transmitted pulse (and had the worst-case polarity), the received pulse is reduced from >1.0 V to 0.75 V, still well above the 0.5 V sensing threshold of the decoder.

The preceding magnetic flux density values correspond to specific current magnitudes at given distances away from the [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) transformers[. Figure 19](#page-12-3) expresses these allowable current magnitudes as a function of frequency for selected distances. As shown, th[e ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) is immune and only affected by extremely large currents operated at a high frequency and near the component. For the 1 MHz example, place a 0.5 kA current 5 mm away from the [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) to affect the operation of the component.

Figure 19. Maximum Allowable Current for Various Current to [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) Spacings

POWER CONSUMPTION

The supply current at a given channel of the [ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) isolator is a function of the supply voltage, channel data rate, and channel output load.

For each input channel, the supply current is given by

For each output channel, the supply current is given by

$$
I_{DDO} = I_{DDO\ (Q)} \qquad \qquad f \leq 0.5 f_r
$$

$$
I_{DDO} = (I_{DDO(D)} + (0.5) \times C_L V_{DDO}) \times (2f - f_r) + I_{DDO(Q)} \tag{5-0.5f_r}
$$

where:

IDDI (Q), *IDDO (Q)* are the specified input and output quiescent supply currents (mA).

IDDI (D), *IDDO (D)* are the input and output dynamic supply currents per channel (mA/Mbps).

f is the input logic signal frequency (MHz, half of the input data rate, NRZ signaling).

fr is the input stage refresh rate (Mbps).

CL is the output load capacitance (nF).

V_{DDO} is the output supply voltage (V).

To calculate the total I_{DD1} and I_{DD2} supply current, the supply currents for each input and output channel corresponding to I_{DD1} and I_{DD2} are calculated and totaled[. Figure 6](#page-9-1) provides total input I_{DD1} supply current as a function of data rate for both input channels[. Figure 7](#page-9-2) provides total I_{DD2} supply current as a function of data rate for both outputs loaded with 2 nF capacitance.

INSULATION LIFETIME

All insulation structures eventually break down when subjected to voltage stress over a sufficiently long period. The rate of insulation degradation is dependent on the characteristics of the voltage waveform applied across the insulation. In addition to the testing performed by the regulatory agencies, Analog Devices carries out an extensive set of evaluations to determine the lifetime of the insulation structure within the [ADuM7223.](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf)

Analog Devices performs accelerated life testing using voltage levels higher than the rated continuous working voltage. Acceleration factors for several operating conditions are determined. These factors allow calculation of the time to failure at the actual working voltage.

The values shown i[n Table](#page-7-2) 7 summarize the peak voltage for 50 years of service life for a bipolar ac operating condition. In many cases, the approved working voltage is higher than a 50 year service life voltage. Operation at these high working voltages can lead to shortened insulation life in some cases.

The insulation lifetime of th[e ADuM7223](http://www.analog.com/ADuM7223?doc=ADuM7223.pdf) depends on the voltage waveform type imposed across the isolation barrier. The *i*Coupler insulation structure degrades at different rates depending on whether the waveform is bipolar ac, unipolar ac, or dc. [Figure 20,](#page-13-2) [Figure 21,](#page-13-3) an[d Figure 22](#page-13-4) illustrate these different isolation voltage waveforms.

A bipolar ac voltage environment is the worst case for the *i*Coupler products and is the 50-year operating lifetime that Analog Devices recommends for maximum working voltage. In the case of unipolar ac or dc voltage, the stress on the insulation is significantly lower. This allows operation at higher working voltages while still achieving a 50-year service life. Treat any crossinsulation voltage waveform that does not conform t[o Figure 21](#page-13-3) o[r Figure 22](#page-13-4) as a bipolar ac waveform, and limit its peak voltage to the 50-year lifetime voltage value listed i[n Table 7.](#page-7-2)

Note that the voltage presented i[n Figure 21](#page-13-3) is shown as sinusoidal for illustration purposes only. It is meant to represent any voltage waveform varying between 0 V and some limiting value. The limiting value can be positive or negative, but the voltage cannot cross 0 V.

OUTLINE DIMENSIONS

ORDERING GUIDE

 $1 Z =$ RoHS Compliant Part.

NOTES

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NOTES

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